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March 2013

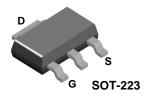
FQT13N06 N-Channel QFET® MOSFET 60 V, 2.8 A, 140 m Ω

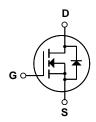
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 2.8 A, 60 V, $R_{DS(on)}$ =140 $m\Omega(Max.)$ @ V_{GS} =10 V, I_D =1.4 A
- Low Gate Charge (Typ. 5.8 nC)
- Low Crss (Typ. 15 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Comple al	Denomentan	FOTANNOC	I I m i t	
Symbol	Parameter		FQT13N06	Unit
V_{DSS}	Drain-Source Voltage		60	V
I_D	Drain Current - Continuous (T _C = 25°C)		2.8	Α
	- Continuous (T _C = 70°C)		2.24	А
I _{DM}	Drain Current - Pulsed	(Note 1)	11.2	А
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	85	mJ
I _{AR}	Avalanche Current	(Note 1)	2.8	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	0.21	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	7.0	V/ns
P _D	Power Dissipation (T _C = 25°C)		2.1	W
	- Derate above 25°C		0.017	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

Symbol	Parameter	Тур	Max	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient *		60	°C/W

^{*} When mounted on the minimum pad size recommended (PCB Mount)

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$	60			V
ΔBV _{DSS} / ΔΤ _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.06		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60 V, V _{GS} = 0 V			1	μΑ
		V _{DS} = 48 V, T _C = 150°C			10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 25 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -25 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Cha	racteristics		·			
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 1.4 \text{ A}$		0.11	0.14	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 25 \text{ V}, I_{D} = 1.4 \text{ A}$ (Note	4)	3.0		S
C _{iss}	Input Capacitance Output Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		240 90	310 120	pF pF
C _{rss}	Reverse Transfer Capacitance	1 = 1.0 MH2		15	20	pF
Switchi	ing Characteristics		1	1		
t _{d(on)}	Turn-On Delay Time	V 20 V I 6.5 Λ		5	20	ns
t _r	Turn-On Rise Time	$V_{DD} = 30 \text{ V}, I_{D} = 6.5 \text{ A},$ $R_{G} = 25 \Omega$		25	60	ns
t _{d(off)}	Turn-Off Delay Time			8	25	ns
t _f	Turn-Off Fall Time	(Note 4	5)	15	40	ns
Q _g	Total Gate Charge	V _{DS} = 48 V, I _D = 13 A,		5.8	7.5	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		2.0		nC
Q _{gd}	Gate-Drain Charge	(Note 4	5)	2.5		nC
	Source Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				2.8	А
I _{SM}	Maximum Pulsed Drain-Source Diode F	num Pulsed Drain-Source Diode Forward Current			11.2	Α
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 2.8 \text{ A}$			1.5	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{S} = 13 \text{ A},$		39		ns
Q _{rr}	Reverse Recovery Charge	$dI_F / dt = 100 A/\mu s$ (Note		40		nC

- **Notes:**1. Repetitive Rating : Pulse width limited by maximum junction temperature 2. L = 12.6mH, I_{AS} = 2.8A, V_{DD} = 25V, R_G = 25 Ω, Starting T_J = 25°C 3. I_{SD} \leq 13A, di/dt \leq 300A/us, V_{DD} \leq BV_{DSS}, Starting T_J = 25°C 4. Pulse Test : Pulse width \leq 300μs, Duty cycle \leq 2% 5. Essentially independent of operating temperature

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Typical Characteristics

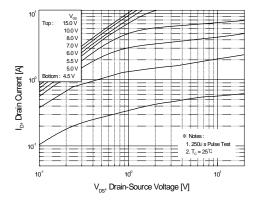


Figure 1. On-Region Characteristics

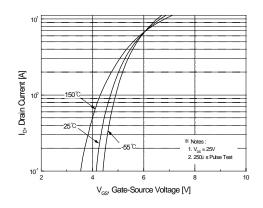


Figure 2. Transfer Characteristics

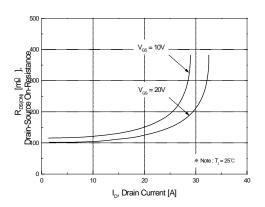


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

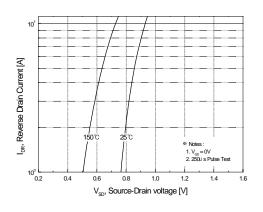


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

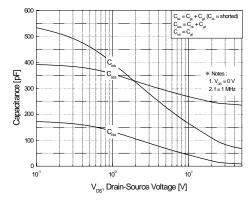


Figure 5. Capacitance Characteristics

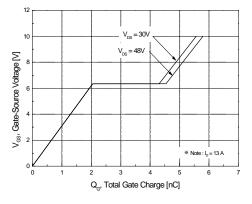
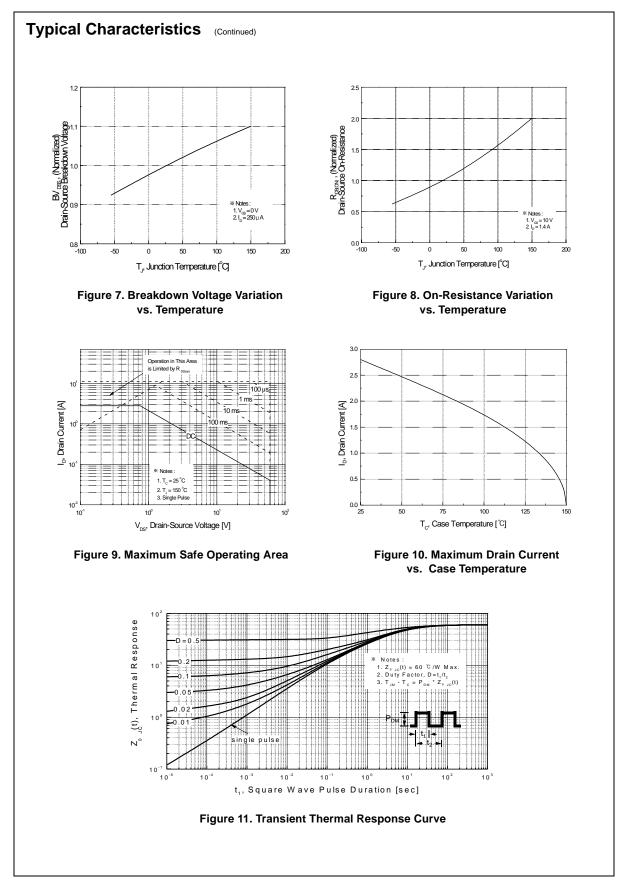
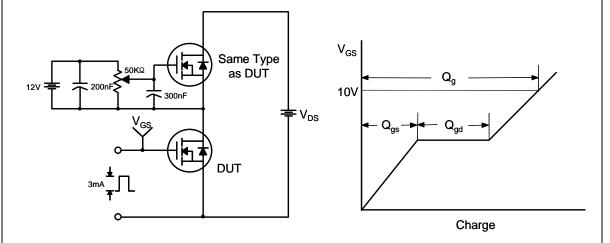


Figure 6. Gate Charge Characteristics

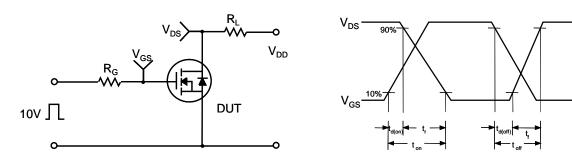


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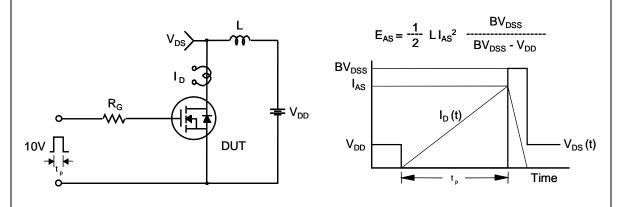
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms



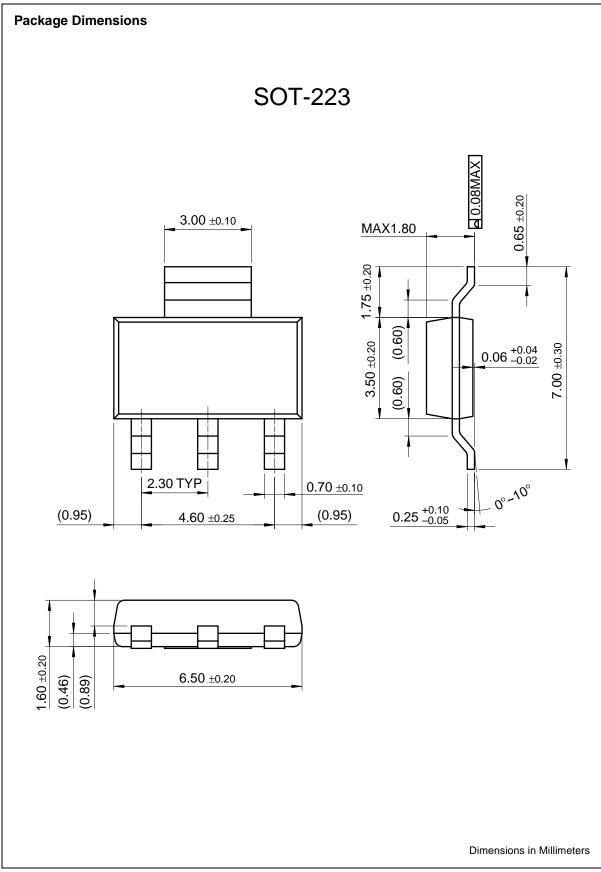
Unclamped Inductive Switching Test Circuit & Waveform



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Peak Diode Recovery dv/dt Test Circuit & Waveforms DUT Driver Same Type as DUT V_{DD} • dv/dt controlled by R_G • I_{SD} controlled by pulse period Gate Pulse Width V_{GS} Gate Pulse Period 10V (Driver) \mathbf{I}_{FM} , Body Diode Forward Current \mathbf{I}_{SD} di/dt (DUT) I_{RM} **Body Diode Reverse Current** V_{DS} (DUT) Body Diode Recovery dv/dt **Body Diode** Forward Voltage Drop

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